TOIREX

XP132A1635SR

ETR1110_001

Power MOSFET

■ GENERAL DESCRIPTION

The XP132A1635SR is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

The small SOP-8 package makes high density mounting possible.

■APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance : $Rds(on)=0.033\,\Omega\,(Vgs=-4.5V)$

: Rds(on)=0.055 Ω (Vgs=-2.5V)

Ultra High-Speed Switching

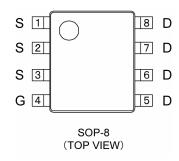
Driving Voltage : -2.5V

P-Channel Power MOSFET

DMOS Structure

Package : SOP-8

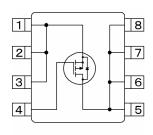
■ PIN CONFIGURATION



■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1~3	S	Source
4	G	Gate
5~8	D	Drain

■EQUIVALENT CIRCUIT



P-channel MOSFET (1 device built-in)

■ ABSOLUTE MAXIMUM RATINGS

Ta = 25°C

1a - 25							
PARAMETER	SYMBOL	RATINGS	UNITS				
Drain-Source Voltage	Vdss	-20	V				
Gate-Source Voltage	Vgss	±12	٧				
Drain Current (DC)	ld	-8	Α				
Drain Current (Pulse)	ldp	-32	Α				
Reverse Drain Current	ldr	-8	Α				
Channel Power Dissipation *	Pd	2.5	W				
Channel Temperature	Tch	150	ပ္				
Storage Temperature Range	Tstg	-55~150	°C				

^{*} When implemented on a glass epoxy PCB

■ELECTRICAL CHARACTERISTICS

DC Characteristics

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	ldss	Vds=-20V, Vgs=0V	-	-	-10	μΑ
Gate-Source Leak Current	Igss	Vgs=±12V, Vds=0V	-	-	±1	μΑ
Gate-Source Cut-Off Voltage	Vgs(off)	Id=-1mA, Vds=-10V	-0.5	-	-1.2	٧
Drain-Source On-State Resistance *	Rds(on)	Id=-4A, Vgs=-4.5V	-	0.025	0.033	Ω
Dialii-Source Oil-State Resistance		Id=-4A, Vgs=-2.5V	-	0.040	0.055	Ω
Forward Transfer Admittance *	Yfs	Id=-4A, Vds=-10V	-	16	-	S
Body Drain Diode Forward Voltage	Vf	If=-8A, Vgs=0V	-	-0.85	-1.1	V

^{*} Effective during pulse test.

Dynamic Characteristics

Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	Ciss	Vds=-10V, Vgs=0V f=1MHz	-	1700	ı	pF
Output Capacitance	Coss		ı	1000	ı	pF
Feedback Capacitance	Crss		ı	500	ı	pF

Switching Characteristics

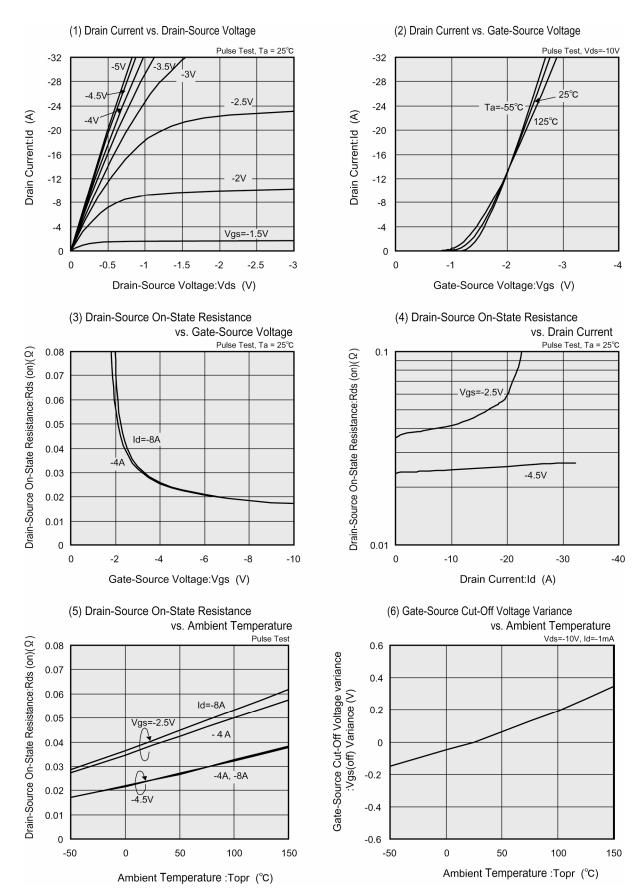
Ta = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	td (on)	Vgs=-5V, Id=-4A Vdd=-10V	ı	15	ı	ns
Rise Time	tr		-	45		ns
Turn-Off Delay Time	td (off)		-	70	-	ns
Fall Time	tf		-	65	-	ns

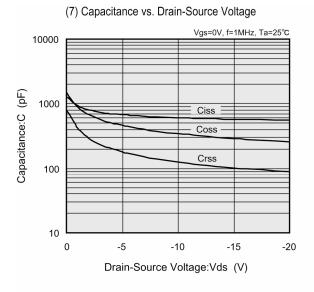
Thermal Characteristics

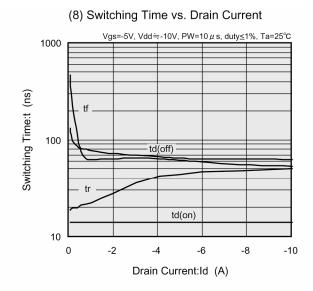
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	Rth (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

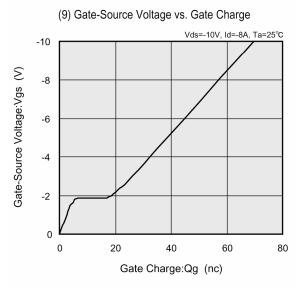
■TYPICAL PERFORMANCE CHARACTERISTICS

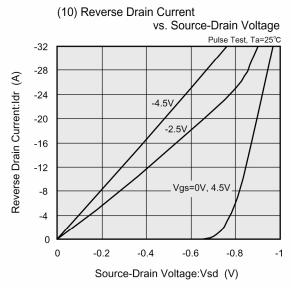


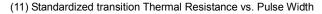
■TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

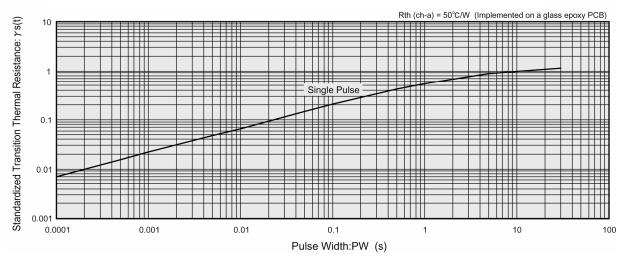












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